

SG - 2BC

The SG - 2BC reflective sensor combines a GaAs IRED with a high - sensitivity phototransistor in a super - mini (4φ) ceramic package, reducing installation space.

FEATURES

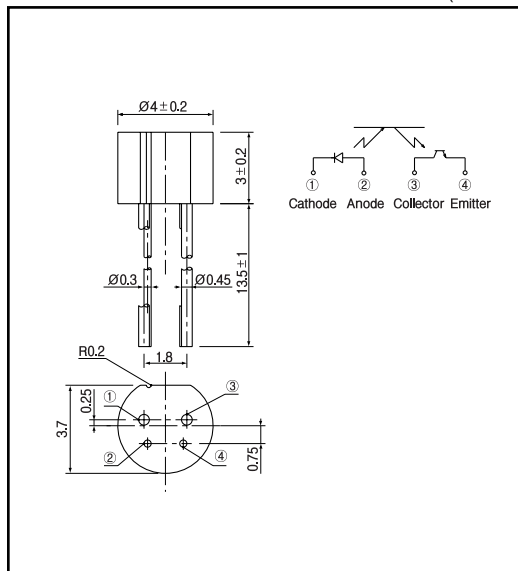
- Compact (ø4mm)
- High performance
- High - speed response
- Easy to mount on P.C.B.
- Widely applicable

APPLICATIONS

- Timing sensors
- Edge sensors
- Micro floppy disk drives
- Level sensors of liquid

DIMENSIONS

(Unit : mm)



MAXIMUM RATINGS

(Ta=25)

Item		Symbol	Rating	Unit
Input	Power dissipation	P_D	75	mW
	Reverse voltage	V_R	5	V
	Forward current	I_F	50	mA
	Pulse forward current ^{†1}	I_{FP}	1	A
Output	Collector power dissipation	P_C	75	mW
	Collector current	I_C	20	mA
	C - E voltage	V_{CEO}	30	V
	E - C voltage	V_{ECO}	3	V
Operating temp.		T_{opr}	- 20 +90	
Storage temp.		$T_{stg.}$	- 30 +100	
Soldering temp.		$T_{sol.}$	260	

*1.t w 100 sec.period :T=10msec.

*2. For MAX. 5 seconds at the position of 2mm from the package

ELECTRO-OPTICAL CHARACTERISTICS

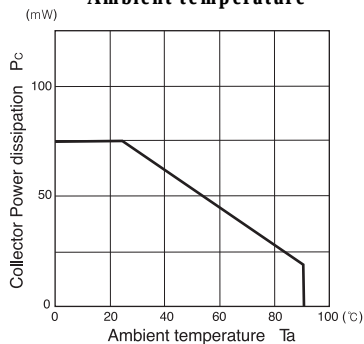
(Ta=25)

Item		Symbol	Conditions	Min.	Typ.	Max.	Unit.
Input	Forward voltage	V_F	$I_F = 4\text{mA}$			1.2	V
	Reverse current	I_R	$V_R = 5\text{V}$			10	μA
	Capacitance	C_t	$V = 0\text{V}, f = 1\text{KHz}$		25		pF
	Peak wavelength	λ_p			940		nm
Output	Collector dark current	I_{CE0}	$V_{CE} = 10\text{V}$			0.1	μA
	Ligh current	I_c	$V_{CE} = 2\text{V}, I_F = 4\text{mA}$		100		μA
	Leakage current	I_{CE0D}	$V_{CE} = 2\text{V}, I_F = 4\text{mA}$			0.1	μA
Switching speeds	Rise time	t_r	$V_{CC} = 2\text{V}, I_c = 100\mu\text{A}, R = 1\text{k}\Omega$		30		$\mu\text{sec.}$
	Fall time	t_f			30		$\mu\text{sec.}$

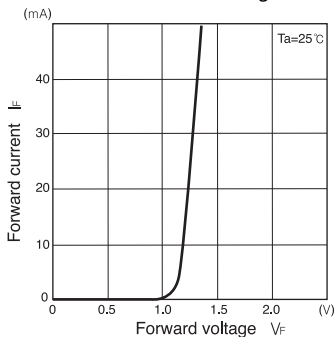
Photo interrupters(Reflective)

SG - 2BC

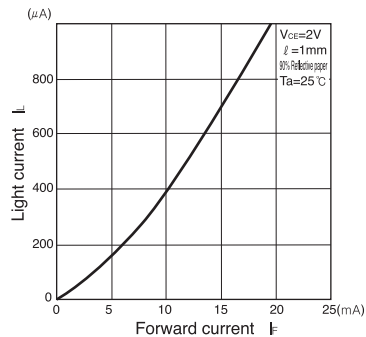
Collector power dissipation Vs. Ambient temperature



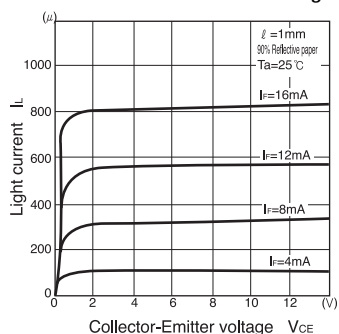
Forward current Vs. Forward voltage



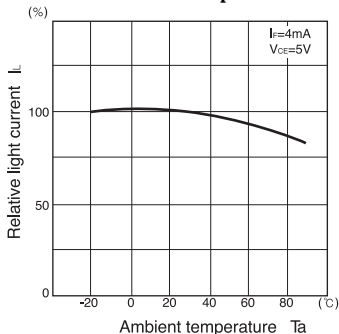
Light current Vs. Forward current



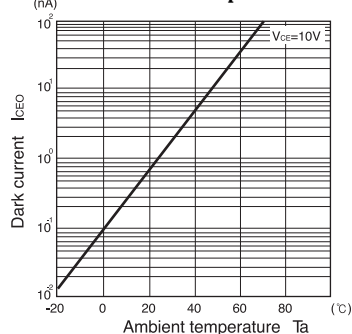
Light current Vs. Collector-Emitter voltage



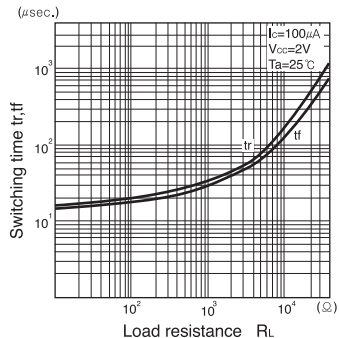
Relative light current Vs. Ambient temperature



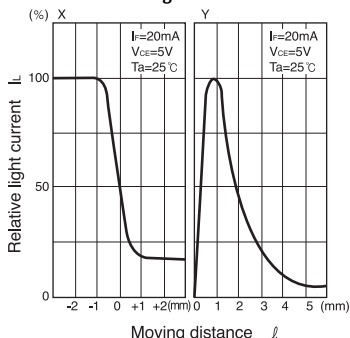
Dark current Vs. Ambient temperature



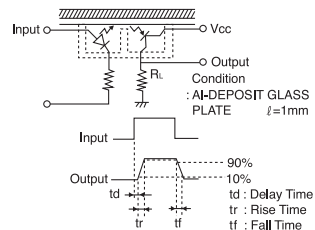
Switching time Vs. Load resistance



Relative light current Vs. Moving distance



Switching time measurement circuit



Method of measuring position characteristic

